

# SN74AXCH1T45 シングル・ビット、デュアル電源バス・トランシーバ、構成可能な電圧変換、3 ステート出力、バス・ホールド入力

## 1 特長

- 完全に構成可能なデュアル・レール設計により、各ポートは 0.65V~3.6V の範囲の電源電圧で動作可能
- 動作温度: -40°C~+125°C
- グリッチの発生しない電源シーケンシング
- データ入力時のバス・ホールドにより、外部のプルアップまたはプルダウン抵抗が不要
- 最大静止電流 ( $I_{CCA} + I_{CCB}$ ): 10 $\mu$ A (最高 85°C) および 16 $\mu$ A (最高 125°C)
- 1.8V から 3.3V への変換時に最高 500Mbps をサポート
- $V_{CC}$  絶縁機能
  - どちらかの  $V_{CC}$  入力が 100mV を下回った場合、すべての I/O 出力がディスエーブルされ高インピーダンス状態に移行
- $I_{off}$  により部分的パワーダウン・モード動作をサポート
- JESD 78, Class II 準拠で 100mA 超のラッチアップ性能
- JESD 22 を超える ESD 保護
  - 8000V、人体モデル
  - 1000V、デバイス帯電モデル

## 2 アプリケーション

- パーソナル・エレクトロニクス
- エンタープライズおよび通信
- ワイヤレス・インフラ
- ビル・オートメーション
- POS システム
- エンタープライズ向けソリッド・ステート・ドライバ

## 3 概要

SN74AXCH1T45 は、別々に構成可能な 2 本の電源レールを採用したシングル・ビットの非反転バス・トランシーバです。このデバイスは、 $V_{CCA}$  電源と  $V_{CCB}$  電源の両方が最低 0.65V で動作します。A ポートは  $V_{CCA}$  (0.65V~3.6V の任意の電圧を入力できます) に追従するように設計されています。同様に B ポートは  $V_{CCB}$  (0.65V~3.6V の任意の電圧を入力できます) に追従するように設計されています。さらに、SN74AXCH1T45 は単一電源システムにも対応しています。

信号伝搬の方向は DIR ピンを使用して制御します。DIR ピンを HIGH に設定するとポート A からポート B への変換になり、DIR ピンを LOW に設定するとポート B からポート A への変換になります。DIR ピンは  $V_{CCA}$  を基準とすることから、そのロジック HIGH とロジック LOW のスレッシュホールドは  $V_{CCA}$  に追従します。

アクティブなバス・ホールド回路により、使用されていない、または駆動されていない入力を有効なロジック状態に保持します。プルアップまたはプルダウン抵抗とバス・ホールド回路との併用は推奨しません。 $V_{CCA}$  または  $V_{CCB}$  に電源が存在する場合、方向制御ピンの状態とは関係なく、バス・ホールド回路はそれぞれ A または B 入力でアクティブ状態を維持します。

このデバイスは、 $I_{off}$  電流を使用する部分的パワーダウン・アプリケーション用に完全に動作が規定されています。 $I_{off}$  保護回路により、電源切断時に入力、出力、複合 I/O は指定の電圧にバイアスされ、それらとの間に過剰な電流が流れることはありません。

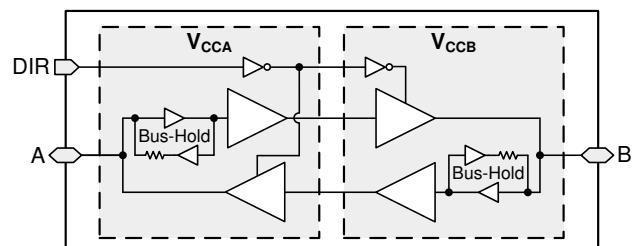
$V_{CC}$  絶縁機能により、 $V_{CCA}$  と  $V_{CCB}$  のどちらかが 100mV を下回ると、両方の出力がディスエーブルになり、両方の I/O ポートが高インピーダンス状態になります。

グリッチの発生しない電源シーケンシングにより、堅牢な電源シーケンシング性能が得られると同時に、どちらの電源レールも任意の順序で電源オン/オフできます。

### 製品情報

部品番号	パッケージ <sup>(1)</sup>	本体サイズ (公称)
SN74AXCH1T45DBV	SOT-23 (6)	2.90mm × 1.60mm
SN74AXCH1T45DCK	SC70 (6)	2.00mm × 1.25mm
SN74AXCH1T45DTQ	X2SON (6)	1.00mm × 0.80mm
SN74AXCH1T45DRY	SON (6)	1.40mm × 1.00mm

- (1) 利用可能なすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。



機能ブロック図



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## 4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

<b>Changes from Revision B (June 2020) to Revision C (September 2020)</b>	<b>Page</b>
• Updated I <sub>CCA</sub> , I <sub>CCB</sub> , and I <sub>CCA</sub> + I <sub>CCB</sub> to reflect updated performance of device.....	6

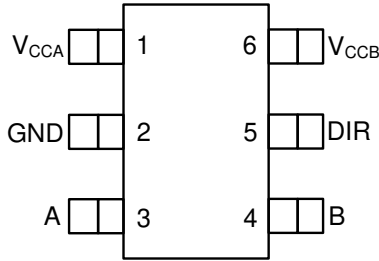
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<b>Changes from Revision A (January 2019) to Revision B (June 2020)</b>	<b>Page</b>
• 「製品情報」表に DRY パッケージ・オプションを追加.....	1
• Added pinout drawing for DRY package.....	3

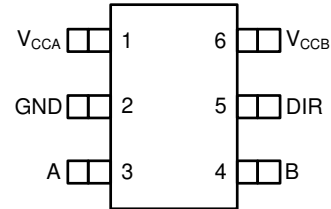
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<b>Changes from Revision * (December 2018) to Revision A (January 2019)</b>	<b>Page</b>
• 「製品情報」表に DBV および DTQ パッケージ・オプションを追加.....	1
• 「改訂履歴」セクションを更新.....	1
• Added pinout drawings for DBV and DTQ packages .....	3
• Added DRY package to Pin Configurations.....	3

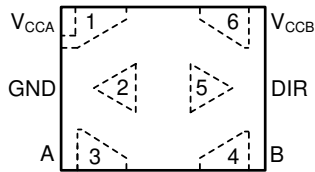
## 5 Pin Configuration and Functions



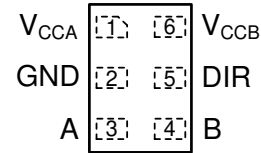
5-1. DBV Package 6-Pin SOT-23 Top View



5-2. DCK Package 6-Pin SC70 Top View



5-3. DTQ Package 6-Pin X2SON Transparent Top View



5-4. DRY Package 6-Pin SON Transparent Top View

### Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	V <sub>CCA</sub>	—	A-port supply voltage. $0.65\text{ V} \leq V_{CCA} \leq 3.6\text{ V}$ .
2	GND	—	Ground
3	A	I/O	Input/output A. This pin is referenced to V <sub>CCA</sub> .
4	B	I/O	Input/output B. This pin is referenced to V <sub>CCB</sub> .
5	DIR	I	Direction control signal. See for functionality.
6	V <sub>CCB</sub>	—	B-port supply voltage. $0.65\text{ V} \leq V_{CCB} \leq 3.6\text{ V}$ .

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CCA</sub>	Supply voltage A		-0.5	4.2	V
V <sub>CCB</sub>	Supply voltage B		-0.5	4.2	V
V <sub>I</sub>	Input Voltage <sup>(2)</sup>	I/O Ports (A Port)	-0.5	4.2	V
		I/O Ports (B Port)	-0.5	4.2	
		Control Inputs	-0.5	4.2	
V <sub>O</sub>	Voltage applied to any output in the high-impedance or power-off state <sup>(2)</sup>	A Port	-0.5	4.2	V
		B Port	-0.5	4.2	
V <sub>O</sub>	Voltage applied to any output in the high or low state <sup>(2) (3)</sup>	A Port	-0.5 V <sub>CCA</sub> + 0.2		V
		B Port	-0.5 V <sub>CCB</sub> + 0.2		
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0	-50		mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0	-50		mA
I <sub>O</sub>	Continuous output current		-50	50	mA
	Continuous current through V <sub>CC</sub> or GND		-100	100	mA
T <sub>J</sub>	Junction Temperature			150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The output positive-voltage rating may be exceeded up to 4.2 V maximum if the output current rating is observed.

### 6.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±8000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1) (2) (3)</sup>

			MIN	MAX	UNIT
V <sub>CCA</sub>	Supply voltage A		0.65	3.6	V
V <sub>CCB</sub>	Supply voltage B		0.65	3.6	V
V <sub>IH</sub>	High-level input voltage	Data Inputs	V <sub>CCI</sub> = 0.65 V - 0.75 V	V <sub>CCI</sub> × 0.70	V
			V <sub>CCI</sub> = 0.76 V - 1 V	V <sub>CCI</sub> × 0.70	
			V <sub>CCI</sub> = 1.1 V - 1.95 V	V <sub>CCI</sub> × 0.65	
			V <sub>CCI</sub> = 2.3 V - 2.7 V	1.6	
			V <sub>CCI</sub> = 3 V - 3.6 V	2	
		Control Input (DIR) Referenced to V <sub>CCA</sub>	V <sub>CCA</sub> = 0.65 V - 0.75 V	V <sub>CCA</sub> × 0.70	
			V <sub>CCA</sub> = 0.76 V - 1 V	V <sub>CCA</sub> × 0.70	
			V <sub>CCA</sub> = 1.1 V - 1.95 V	V <sub>CCA</sub> × 0.65	
			V <sub>CCA</sub> = 2.3 V - 2.7 V	1.6	
			V <sub>CCA</sub> = 3 V - 3.6 V	2	
V <sub>IL</sub>	Low-level input voltage	Data Inputs	V <sub>CCI</sub> = 0.65 V - 0.75 V	V <sub>CCI</sub> × 0.30	V
			V <sub>CCI</sub> = 0.76 V - 1 V	V <sub>CCI</sub> × 0.30	
			V <sub>CCI</sub> = 1.1 V - 1.95 V	V <sub>CCI</sub> × 0.35	
			V <sub>CCI</sub> = 2.3 V - 2.7 V	0.7	
			V <sub>CCI</sub> = 3 V - 3.6 V	0.8	
		Control Input (DIR) Referenced to V <sub>CCA</sub>	V <sub>CCA</sub> = 0.65 V - 0.75 V	V <sub>CCA</sub> × 0.30	
			V <sub>CCA</sub> = 0.76 V - 1 V	V <sub>CCA</sub> × 0.30	
			V <sub>CCA</sub> = 1.1 V - 1.95 V	V <sub>CCA</sub> × 0.35	
			V <sub>CCA</sub> = 2.3 V - 2.7 V	0.7	
			V <sub>CCA</sub> = 3 V - 3.6 V	0.8	
V <sub>I</sub>	Input voltage <sup>(3)</sup>		0	3.6	V
V <sub>O</sub>	Output voltage	Active State	0	V <sub>CCO</sub>	V
		Tri-State	0	3.6	
Δt/Δv	Input transition rate			100	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

(1) V<sub>CCI</sub> is the VCC associated with the input port.

(2) V<sub>CCO</sub> is the VCC associated with the output port.

(3) All unused inputs of the device must be held at VCC or GND to ensure proper device operation. Refer to the TI application report, [Implications of Slow or Floating CMOS Inputs](#).

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>	SN74AXCH1T45				UNIT	
	DBV (SOT-23)	DCK (SC70)	DTQ (X2SON)	DRY (SON)		
	6 PINS	6 PINS	6 PINS	6 PINS		
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	214.0	223.9	327.8	308.3	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	151.8	150.9	194.9	206.4	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	93.6	75.3	248.4	181.7	°C/W
ψ <sub>JT</sub>	Junction-to-top characterization parameter	78.1	58.2	24.1	42.6	°C/W
ψ <sub>JB</sub>	Junction-to-board characterization parameter	93.4	75.0	247.6	180.8	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup> <sup>(2)</sup>

PARAMETER	TEST CONDITIONS	V <sub>CCA</sub>	V <sub>CCB</sub>	Operating free-air temperature (T <sub>A</sub> )						UNIT				
				–40°C to 85°C			–40°C to 125°C							
				MIN	TYP <sup>(3)</sup>	MAX	MIN	TYP	MAX					
V <sub>OH</sub>	High-level output voltage V <sub>I</sub> = V <sub>IH</sub>	0.7 V - 3.6 V	0.7 V - 3.6 V	V <sub>CCO</sub> –0.1			V <sub>CCO</sub> –0.1		V					
										I <sub>OH</sub> = –100 μA	0.65 V	0.65 V	0.55	0.55
										I <sub>OH</sub> = –200 μA	0.76 V	0.76 V	0.58	0.58
										I <sub>OH</sub> = –500 μA	0.85 V	0.85 V	0.65	0.65
										I <sub>OH</sub> = –3 mA	1.1 V	1.1 V	0.85	0.85
										I <sub>OH</sub> = –6 mA	1.4 V	1.4 V	1.05	1.05
										I <sub>OH</sub> = –8 mA	1.65 V	1.65 V	1.2	1.2
										I <sub>OH</sub> = –9 mA	2.3 V	2.3 V	1.75	1.75
										I <sub>OH</sub> = –12 mA	3 V	3 V	2.3	2.3
V <sub>OL</sub>	Low-level output voltage V <sub>I</sub> = V <sub>IL</sub>	0.7 V - 3.6 V	0.7 V - 3.6 V					V						
									I <sub>OL</sub> = 100 μA	0.65 V	0.65 V	0.1	0.1	
									I <sub>OL</sub> = 50 μA	0.76 V	0.76 V	0.18	0.18	
									I <sub>OL</sub> = 200 μA	0.85 V	0.85 V	0.2	0.2	
									I <sub>OL</sub> = 3 mA	1.1 V	1.1 V	0.25	0.25	
									I <sub>OL</sub> = 6 mA	1.4 V	1.4 V	0.35	0.35	
									I <sub>OL</sub> = 8 mA	1.65 V	1.65 V	0.45	0.45	
									I <sub>OL</sub> = 9 mA	2.3 V	2.3 V	0.55	0.55	
									I <sub>OL</sub> = 12 mA	3 V	3 V	0.7	0.7	
I <sub>BHL</sub>	Bus-hold low sustaining current <sup>(4)</sup>	V <sub>I</sub> = 0.20 V	0.65 V	0.65 V	4		4	μA						
									V <sub>I</sub> = 0.23 V	0.76 V	0.76 V	8	7	
									V <sub>I</sub> = 0.26 V	0.85 V	0.85 V	10	10	
									V <sub>I</sub> = 0.39 V	1.1 V	1.1 V	20	20	
									V <sub>I</sub> = 0.49 V	1.4 V	1.4 V	40	30	
									V <sub>I</sub> = 0.58 V	1.65 V	1.65 V	55	45	
									V <sub>I</sub> = 0.7 V	2.3 V	2.3 V	90	80	
									V <sub>I</sub> = 0.8 V	3 V	3 V	145	135	
I <sub>BHH</sub>	Bus-hold high sustaining current <sup>(5)</sup>	V <sub>I</sub> = 0.45 V	0.65 V	0.65 V	–4		–4	μA						
									V <sub>I</sub> = 0.53 V	0.76 V	0.76 V	–8	–7	
									V <sub>I</sub> = 0.59 V	0.85 V	0.85 V	–10	–10	
									V <sub>I</sub> = 0.71 V	1.1 V	1.1 V	–20	–20	
									V <sub>I</sub> = 0.91 V	1.4 V	1.4 V	–40	–30	
									V <sub>I</sub> = 1.07 V	1.65 V	1.65 V	–55	–45	
									V <sub>I</sub> = 1.6 V	2.3 V	2.3 V	–90	–80	
									V <sub>I</sub> = 2.0 V	3 V	3 V	–145	–135	

## 6.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup> <sup>(2)</sup>

PARAMETER	TEST CONDITIONS	V <sub>CCA</sub>	V <sub>CCB</sub>	Operating free-air temperature (T <sub>A</sub> )					UNIT	
				–40°C to 85°C			–40°C to 125°C			
				MIN	TYP <sup>(3)</sup>	MAX	MIN	TYP		MAX
I <sub>BHLO</sub>	Bus-hold low overdrive current <sup>(6)</sup>	V <sub>I</sub> = 0 to V <sub>CC</sub>	0.75 V	0.75 V	40			40		μA
			0.84 V	0.84 V	50			50		
			0.95 V	0.95 V	65			65		
			1.3 V	1.3 V	105			105		
			1.6 V	1.6 V	150			150		
			1.95 V	1.95 V	205			205		
			2.7 V	2.7 V	335			335		
I <sub>BHHO</sub>	Bus-hold high overdrive current <sup>(7)</sup>	V <sub>I</sub> = 0 to V <sub>CC</sub>	0.75 V	0.75 V	–40			–40		μA
			0.84 V	0.84 V	–50			–50		
			0.95 V	0.95 V	–65			–65		
			1.3 V	1.3 V	–105			–105		
			1.6 V	1.6 V	–150			–150		
			1.95 V	1.95 V	–205			–205		
			2.7 V	2.7 V	–335			–335		
I <sub>I</sub>	Input leakage current	Control input (DIR): V <sub>I</sub> = V <sub>CCA</sub> or GND	0.65 V - 3.6 V	0.65 V - 3.6 V	–0.5	0.5	–1	1	μA	
		A or B Port: V <sub>i</sub> = V <sub>CCI</sub> or GND	0.65 V - 3.6 V	0.65 V - 3.6 V	–4	4	–8	8		
I <sub>off</sub>	Partial power down current	A or B Port: V <sub>i</sub> or V <sub>o</sub> = 0 V - 3.6 V	0 V	0 V - 3.6 V	–8	8	–12	12	μA	
			0 V - 3.6 V	0 V	–8	8	–12	12		
I <sub>CCA</sub>	V <sub>CCA</sub> supply current	V <sub>I</sub> = V <sub>CCI</sub> or GND	I <sub>o</sub> = 0	0.65 V - 3.6 V	0.65 V - 3.6 V	8			12	μA
				0 V	3.6 V	–2			–8	
				3.6 V	0 V	2			8	
I <sub>CCB</sub>	V <sub>CCB</sub> supply current	V <sub>I</sub> = V <sub>CCI</sub> or GND	I <sub>o</sub> = 0	0.65 V - 3.6 V	0.65 V - 3.6 V	8			12	μA
				0 V	3.6 V	2			8	
				3.6 V	0 V	–2			–8	
I <sub>CCA</sub> + I <sub>CCB</sub>	Combined supply current	V <sub>I</sub> = V <sub>CCI</sub> or GND	I <sub>o</sub> = 0	0.65 V - 3.6 V	0.65 V - 3.6 V	10			16	μA
C <sub>i</sub>	Control input capacitance	V <sub>I</sub> = 3.3 V or GND		3.3 V	3.3 V	4.3			4.3	pF
C <sub>io</sub>	Data I/O capacitance, A Port	V <sub>O</sub> = 1.65 V DC +1 MHz -16 dBm sine wave		3.3 V	0 V	7.4			7.4	pF
C <sub>io</sub>	Data I/O capacitance, B Port	V <sub>O</sub> = 1.65 V DC +1 MHz -16 dBm sine wave		0 V	3.3 V	7.4			7.4	pF

(1) V<sub>CCI</sub> is the VCC associated with the input port.

(2) V<sub>CCO</sub> is the VCC associated with the output port.

(3) All typical data is taken at 25°C.

(4) The bus-hold circuit can sink at least the minimum low sustaining current at V<sub>IL</sub>(MAX). I<sub>BHL</sub> should be measured after lowering V<sub>I</sub> to GND and then raising it to V<sub>IL</sub>(MAX).

(5) The bus-hold circuit can source at least the minimum high sustaining current at V<sub>IH</sub>(MIN). I<sub>BHH</sub> should be measured after raising V<sub>I</sub> to V<sub>CC</sub> and then lowering it to V<sub>IH</sub>(MIN).

(6) An external driver must source at least I<sub>BHLO</sub> to switch this node from low to high.

(7) An external driver must sink at least I<sub>BHHO</sub> to switch this node from high to low.

表 6-1. Switching Characteristics,  $V_{CCA} = 0.7\text{ V}$ 

$t_{pd}$	Propagation delay	A	B	-40°C to 85°C	0.5	181	0.5	119	0.5	85	0.5	51	0.5	49	0.5	52	0.5	65	0.5	152	ns
				-40°C to 125°C	0.5	181	0.5	119	0.5	85	0.5	51	0.5	49	0.5	52	0.5	65	0.5	152	
	B	A	-40°C to 85°C	0.5	181	0.5	162	0.5	136	0.5	96	0.5	91	0.5	89	0.5	88	0.5	88		
			-40°C to 125°C	0.5	181	0.5	162	0.5	136	0.5	96	0.5	91	0.5	89	0.5	88	0.5	88		
$t_{dis}$	Disable time	DIR	A	-40°C to 85°C	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	ns
				-40°C to 125°C	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	0.5	152	
	DIR	B	-40°C to 85°C	0.5	170	0.5	127	0.5	102	0.5	48	0.5	42	0.5	46	0.5	58	0.5	108		
			-40°C to 125°C	0.5	170	0.5	127	0.5	102	0.5	48	0.5	42	0.5	46	0.5	58	0.5	108		
$t_{en}$	Enable time	DIR	A	-40°C to 85°C	0.5	343	0.5	278	0.5	231	0.5	141	0.5	132	0.5	134	0.5	144	0.5	193	ns
				-40°C to 125°C	0.5	343	0.5	278	0.5	231	0.5	141	0.5	132	0.5	134	0.5	144	0.5	193	
	DIR	B	-40°C to 85°C	0.5	326	0.5	257	0.5	222	0.5	194	0.5	191	0.5	191	0.5	197	0.5	277		
			-40°C to 125°C	0.5	326	0.5	257	0.5	222	0.5	194	0.5	191	0.5	191	0.5	197	0.5	277		

表 6-2. Switching Characteristics,  $V_{CCA} = 0.8\text{ V}$ 

$t_{pd}$	Propagation delay	A	B	-40°C to 85°C	0.5	162	0.5	98	0.5	65	0.5	33	0.5	28	0.5	26	0.5	27	0.5	37	ns
				-40°C to 125°C	0.5	162	0.5	98	0.5	65	0.5	33	0.5	28	0.5	26	0.5	27	0.5	37	
	B	A	-40°C to 85°C	0.5	119	0.5	98	0.5	81	0.5	54	0.5	45	0.5	44	0.5	43	0.5	42		
			-40°C to 125°C	0.5	119	0.5	98	0.5	81	0.5	54	0.5	45	0.5	44	0.5	43	0.5	42		
$t_{dis}$	Disable time	DIR	A	-40°C to 85°C	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	ns
				-40°C to 125°C	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	0.5	107	
	DIR	B	-40°C to 85°C	0.5	160	0.5	117	0.5	90	0.5	39	0.5	31	0.5	29	0.5	29	0.5	37		
			-40°C to 125°C	0.5	160	0.5	117	0.5	90	0.5	39	0.5	31	0.5	29	0.5	29	0.5	37		
$t_{en}$	Enable time	DIR	A	-40°C to 85°C	0.5	268	0.5	205	0.5	165	0.5	90	0.5	74	0.5	71	0.5	70	0.5	77	ns
				-40°C to 125°C	0.5	268	0.5	205	0.5	165	0.5	90	0.5	74	0.5	71	0.5	70	0.5	77	
	DIR	B	-40°C to 85°C	0.5	257	0.5	194	0.5	161	0.5	130	0.5	125	0.5	126	0.5	125	0.5	132		
			-40°C to 125°C	0.5	257	0.5	194	0.5	161	0.5	130	0.5	125	0.5	126	0.5	125	0.5	132		



**表 6-3. Switching Characteristics,  $V_{CCA} = 0.9\text{ V}$**

$t_{pd}$	A	B	-40°C to 85°C	0.5	135	0.5	81	0.5	54	0.5	24	0.5	18	0.5	17	0.5	15	0.5	18	ns		
			-40°C to 125°C	0.5	135	0.5	81	0.5	54	0.5	24	0.5	18	0.5	17	0.5	15	0.5	18			
	B	A	-40°C to 85°C	0.5	86	0.5	65	0.5	54	0.5	41	0.5	30	0.5	26	0.5	23	0.5	23			
			-40°C to 125°C	0.5	86	0.5	65	0.5	54	0.5	41	0.5	30	0.5	26	0.5	23	0.5	23			
$t_{dis}$	DIR	A	-40°C to 85°C	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	ns
			-40°C to 125°C	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79	0.5	79			
	DIR	B	-40°C to 85°C	0.5	154	0.5	111	0.5	85	0.5	34	0.5	27	0.5	25	0.5	21	0.5	23			
			-40°C to 125°C	0.5	154	0.5	111	0.5	85	0.5	34	0.5	27	0.5	25	0.5	21	0.5	23			
$t_{en}$	DIR	A	-40°C to 85°C	0.5	227	0.5	166	0.5	131	0.5	71	0.5	53	0.5	48	0.5	42	0.5	44	ns		
			-40°C to 125°C	0.5	227	0.5	166	0.5	131	0.5	71	0.5	53	0.5	48	0.5	42	0.5	44			
	DIR	B	-40°C to 85°C	0.5	206	0.5	152	0.5	125	0.5	96	0.5	91	0.5	89	0.5	89	0.5	92			
			-40°C to 125°C	0.5	206	0.5	152	0.5	125	0.5	96	0.5	91	0.5	89	0.5	89	0.5	92			

**表 6-4. Switching Characteristics,  $V_{CCA} = 1.2\text{ V}$**

$t_{pd}$	A	B	-40°C to 85°C	0.5	95	0.5	54	0.5	41	0.5	16	0.5	11	0.5	9	0.5	8	0.5	8	ns		
			-40°C to 125°C	0.5	95	0.5	54	0.5	41	0.5	16	0.5	11	0.5	9	0.5	8	0.5	8			
	B	A	-40°C to 85°C	0.5	51	0.5	33	0.5	24	0.5	16	0.5	13	0.5	11	0.5	8	0.5	8			
			-40°C to 125°C	0.5	51	0.5	33	0.5	24	0.5	16	0.5	13	0.5	11	0.5	8	0.5	8			
$t_{dis}$	DIR	A	-40°C to 85°C	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	ns
			-40°C to 125°C	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28	0.5	28			
	DIR	B	-40°C to 85°C	0.5	148	0.5	105	0.5	78	0.5	30	0.5	23	0.5	20	0.5	16	0.5	16			
			-40°C to 125°C	0.5	148	0.5	105	0.5	78	0.5	30	0.5	23	0.5	20	0.5	16	0.5	16			
$t_{en}$	DIR	A	-40°C to 85°C	0.5	191	0.5	129	0.5	96	0.5	43	0.5	34	0.5	30	0.5	23	0.5	22	ns		
			-40°C to 125°C	0.5	191	0.5	129	0.5	96	0.5	43	0.5	34	0.5	30	0.5	23	0.5	22			
	DIR	B	-40°C to 85°C	0.5	116	0.5	75	0.5	61	0.5	41	0.5	37	0.5	36	0.5	35	0.5	35			
			-40°C to 125°C	0.5	116	0.5	75	0.5	61	0.5	41	0.5	37	0.5	36	0.5	35	0.5	35			

**表 6-5. Switching Characteristics,  $V_{CCA} = 1.5\text{ V}$**

$t_{pd}$	Propagation delay	A	B	-40°C to 85°C	0.5	91	0.5	45	0.5	30	0.5	13	0.5	9	0.5	8	0.5	6	0.5	6	ns
				-40°C to 125°C	0.5	91	0.5	45	0.5	30	0.5	13	0.5	9	0.5	8	0.5	6	0.5	6	
	B	A	-40°C to 85°C	0.5	49	0.5	28	0.5	18	0.5	11	0.5	9	0.5	8	0.5	6	0.5	5		
				-40°C to 125°C	0.5	49	0.5	28	0.5	18	0.5	11	0.5	9	0.5	8	0.5	6	0.5	5	
$t_{dis}$	Disable time	DIR	A	-40°C to 85°C	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	ns
					-40°C to 125°C	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20	0.5	20		
	DIR	B	-40°C to 85°C	0.5	146	0.5	103	0.5	76	0.5	28	0.5	21	0.5	19	0.5	15	0.5	14		
				-40°C to 125°C	0.5	146	0.5	103	0.5	76	0.5	28	0.5	21	0.5	19	0.5	15	0.5	14	
$t_{en}$	Enable time	DIR	A	-40°C to 85°C	0.5	186	0.5	124	0.5	89	0.5	38	0.5	29	0.5	26	0.5	20	0.5	18	ns
					-40°C to 125°C	0.5	186	0.5	124	0.5	89	0.5	38	0.5	29	0.5	26	0.5	20	0.5	
	DIR	B	-40°C to 85°C	0.5	104	0.5	58	0.5	43	0.5	31	0.5	28	0.5	27	0.5	25	0.5	25		
				-40°C to 125°C	0.5	104	0.5	58	0.5	43	0.5	31	0.5	28	0.5	27	0.5	25	0.5	25	

**表 6-6. Switching Characteristics,  $V_{CCA} = 1.8\text{ V}$**

$t_{pd}$	Propagation delay	A	B	-40°C to 85°C	0.5	89	0.5	44	0.5	26	0.5	11	0.5	8	0.5	7	0.5	6	0.5	5	ns
				-40°C to 125°C	0.5	89	0.5	44	0.5	26	0.5	11	0.5	8	0.5	7	0.5	6	0.5	5	
	B	A	-40°C to 85°C	0.5	52	0.5	26	0.5	17	0.5	9	0.5	8	0.5	7	0.5	6	0.5	5		
				-40°C to 125°C	0.5	52	0.5	26	0.5	17	0.5	9	0.5	8	0.5	7	0.5	6	0.5	5	
$t_{dis}$	Disable time	DIR	A	-40°C to 85°C	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	ns
					-40°C to 125°C	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17	0.5	17		
	DIR	B	-40°C to 85°C	0.5	147	0.5	103	0.5	76	0.5	27	0.5	20	0.5	18	0.5	14	0.5	13		
				-40°C to 125°C	0.5	147	0.5	103	0.5	76	0.5	27	0.5	20	0.5	18	0.5	14	0.5	13	
$t_{en}$	Enable time	DIR	A	-40°C to 85°C	0.5	185	0.5	122	0.5	86	0.5	35	0.5	27	0.5	24	0.5	19	0.5	17	ns
					-40°C to 125°C	0.5	185	0.5	122	0.5	86	0.5	35	0.5	27	0.5	24	0.5	19	0.5	
	DIR	B	-40°C to 85°C	0.5	100	0.5	54	0.5	37	0.5	27	0.5	25	0.5	24	0.5	22	0.5	22		
				-40°C to 125°C	0.5	100	0.5	54	0.5	37	0.5	27	0.5	25	0.5	24	0.5	22	0.5	22	

**表 6-7. Switching Characteristics,  $V_{CCA} = 2.5\text{ V}$**

$t_{pd}$	Propagation delay	A	B	-40°C to 85°C	0.5	88	0.5	42	0.5	23	0.5	8	0.5	6	0.5	6	0.5	5	0.5	5	ns		
				-40°C to 125°C	0.5	88	0.5	42	0.5	23	0.5	8	0.5	6	0.5	6	0.5	6	0.5	5		0.5	5
	B	A	-40°C to 85°C	0.5	65	0.5	27	0.5	15	0.5	8	0.5	6	0.5	6	0.5	6	0.5	5	0.5		4	
			-40°C to 125°C	0.5	65	0.5	27	0.5	15	0.5	8	0.5	6	0.5	6	0.5	6	0.5	5	0.5		4	
$t_{dis}$	Disable time	DIR	A	-40°C to 85°C	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	ns
				-40°C to 125°C	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	0.5	13	
	B	DIR	-40°C to 85°C	0.5	146	0.5	102	0.5	75	0.5	27	0.5	19	0.5	17	0.5	17	0.5	13	0.5	12		
			-40°C to 125°C	0.5	146	0.5	102	0.5	75	0.5	27	0.5	19	0.5	17	0.5	17	0.5	13	0.5	12		
$t_{en}$	Enable time	DIR	A	-40°C to 85°C	0.5	191	0.5	122	0.5	85	0.5	33	0.5	25	0.5	22	0.5	17	0.5	16	ns		
				-40°C to 125°C	0.5	191	0.5	122	0.5	85	0.5	33	0.5	25	0.5	22	0.5	22	0.5	17		0.5	16
	B	DIR	-40°C to 85°C	0.5	95	0.5	50	0.5	31	0.5	20	0.5	18	0.5	17	0.5	17	0.5	17	0.5		17	
			-40°C to 125°C	0.5	95	0.5	50	0.5	31	0.5	20	0.5	18	0.5	17	0.5	17	0.5	17	0.5		17	

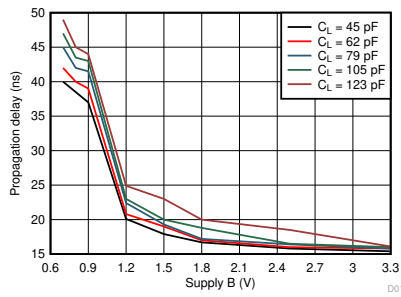
**表 6-8. Switching Characteristics,  $V_{CCA} = 3.3\text{ V}$**

$t_{pd}$	Propagation delay	A	B	-40°C to 85°C	0.5	87	0.5	42	0.5	23	0.5	8	0.5	5	0.5	5	0.5	4	0.5	4	ns		
				-40°C to 125°C	0.5	87	0.5	42	0.5	23	0.5	8	0.5	5	0.5	5	0.5	5	0.5	4		0.5	4
	B	A	-40°C to 85°C	0.5	154	0.5	37	0.5	18	0.5	8	0.5	6	0.5	5	0.5	5	0.5	5	0.5		4	
			-40°C to 125°C	0.5	154	0.5	37	0.5	18	0.5	8	0.5	6	0.5	5	0.5	5	0.5	5	0.5		4	
$t_{dis}$	Disable time	DIR	A	-40°C to 85°C	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	ns
				-40°C to 125°C	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	0.5	12	
	B	DIR	-40°C to 85°C	0.5	147	0.5	102	0.5	75	0.5	26	0.5	19	0.5	17	0.5	17	0.5	13	0.5	12		
			-40°C to 125°C	0.5	147	0.5	102	0.5	75	0.5	26	0.5	19	0.5	17	0.5	17	0.5	13	0.5	12		
$t_{en}$	Enable time	DIR	A	-40°C to 85°C	0.5	275	0.5	129	0.5	88	0.5	34	0.5	24	0.5	21	0.5	17	0.5	16	ns		
				-40°C to 125°C	0.5	275	0.5	129	0.5	88	0.5	34	0.5	24	0.5	21	0.5	21	0.5	17		0.5	16
	B	DIR	-40°C to 85°C	0.5	94	0.5	49	0.5	30	0.5	18	0.5	16	0.5	16	0.5	16	0.5	15	0.5		15	
			-40°C to 125°C	0.5	94	0.5	49	0.5	30	0.5	18	0.5	16	0.5	16	0.5	16	0.5	15	0.5		15	

## 6.6 Operating Characteristics: $T_A = 25^\circ\text{C}$

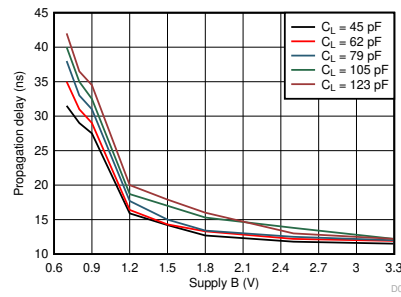
PARAMETER		TEST CONDITIONS	$V_{CCA}$	$V_{CCB}$	MIN	TYP	MAX	UNIT
$C_{pdA}$	Power Dissipation Capacitance per transceiver (A to B: outputs enabled)	CL = 0, RL = Open f = 1 MHz, tr = tf = 1 ns	0.7 V	0.7 V		2.0		pF
			0.8 V	0.8 V		2.0		
			0.9 V	0.9 V		2.0		
			1.2 V	1.2 V		2.0		
			1.5 V	1.5 V		1.9		
			1.8 V	1.8 V		2.0		
			2.5 V	2.5 V		2.4		
			3.3 V	3.3 V		3.0		
	Power Dissipation Capacitance per transceiver (B to A: outputs enabled)	CL = 0, RL = Open f = 1 MHz, tr = tf = 1 ns	0.7 V	0.7 V		12		pF
			0.8 V	0.8 V		12		
			0.9 V	0.9 V		12		
			1.2 V	1.2 V		12		
			1.5 V	1.5 V		13		
			1.8 V	1.8 V		13		
			2.5 V	2.5 V		17		
3.3 V			3.3 V		21			
$C_{pdB}$	Power Dissipation Capacitance per transceiver (A to B: outputs enabled)	CL = 0, RL = Open f = 1 MHz, tr = tf = 1 ns	0.7 V	0.7 V		12		pF
			0.8 V	0.8 V		12		
			0.9 V	0.9 V		12		
			1.2 V	1.2 V		12		
			1.5 V	1.5 V		13		
			1.8 V	1.8 V		13		
			2.5 V	2.5 V		17		
			3.3 V	3.3 V		21		
	Power Dissipation Capacitance per transceiver (B to A: outputs enabled)	CL = 0, RL = Open f = 1 MHz, tr = tf = 1 ns	0.7 V	0.7 V		2.1		pF
			0.8 V	0.8 V		2.2		
			0.9 V	0.9 V		2.2		
			1.2 V	1.2 V		2.2		
			1.5 V	1.5 V		2.3		
			1.8 V	1.8 V		2.3		
			2.5 V	2.5 V		2.6		
3.3 V			3.3 V		3.3			

## 6.7 Typical Characteristics



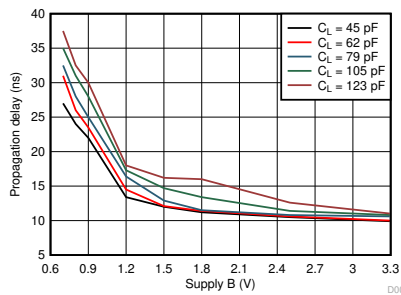
$T_A = 25^\circ\text{C}$   $V_{CCA} = 0.7\text{ V}$

6-1. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



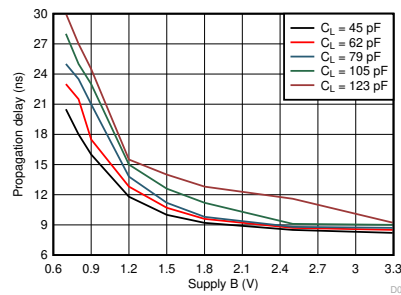
$T_A = 25^\circ\text{C}$   $V_{CCA} = 0.8\text{ V}$

6-2. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



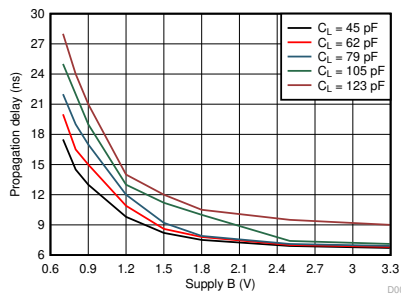
$T_A = 25^\circ\text{C}$   $V_{CCA} = 0.9\text{ V}$

6-3. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



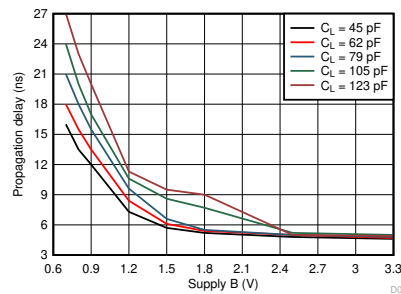
$T_A = 25^\circ\text{C}$   $V_{CCA} = 1.2\text{ V}$

6-4. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



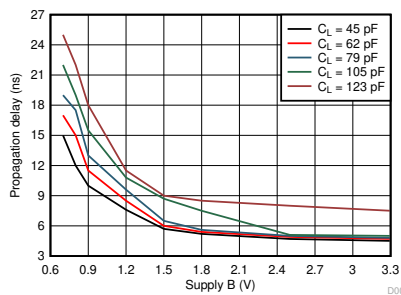
$T_A = 25^\circ\text{C}$   $V_{CCA} = 1.5\text{ V}$

6-5. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



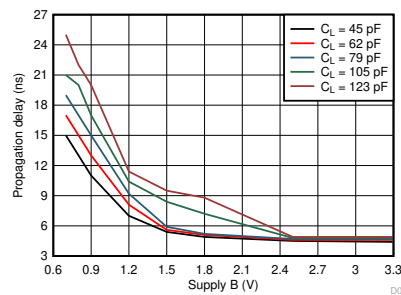
$T_A = 25^\circ\text{C}$   $V_{CCA} = 1.8\text{ V}$

6-6. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



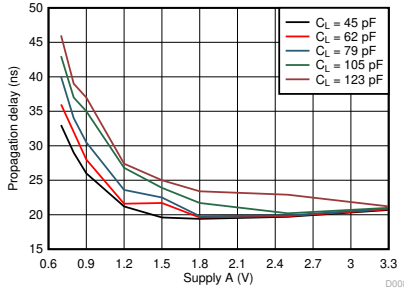
$T_A = 25^\circ\text{C}$   $V_{CCA} = 3.3\text{ V}$

6-7. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



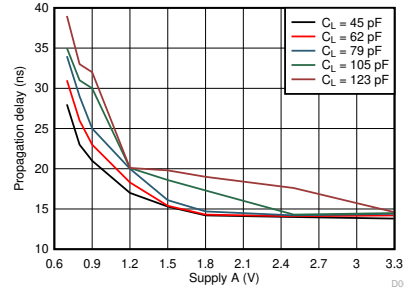
$T_A = 25^\circ\text{C}$   $V_{CCA} = 2.5\text{ V}$

6-8. Typical Propagation Delay of Low-to-High (A to B) vs Load Capacitance



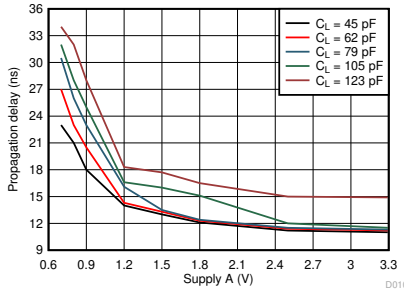
$T_A = 25^\circ\text{C}$   $V_{CCA} = 0.7\text{ V}$

**6-9. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance**



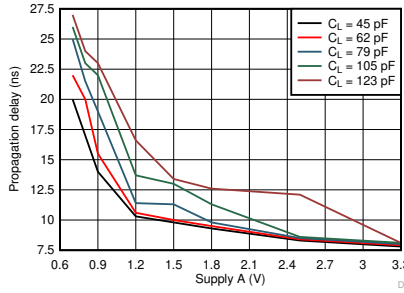
$T_A = 25^\circ\text{C}$   $V_{CCA} = 0.8\text{ V}$

**6-10. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance**



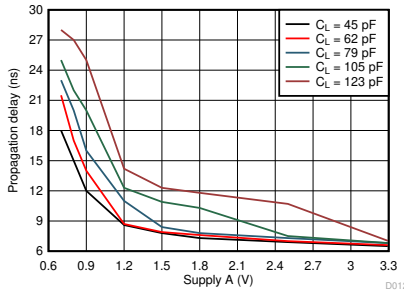
$T_A = 25^\circ\text{C}$   $V_{CCA} = 0.9\text{ V}$

**6-11. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance**



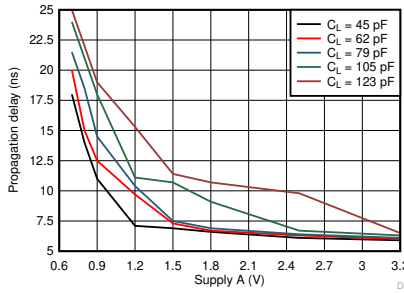
$T_A = 25^\circ\text{C}$   $V_{CCA} = 1.2\text{ V}$

**6-12. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance**



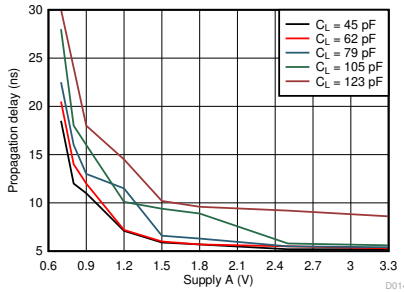
$T_A = 25^\circ\text{C}$   $V_{CCA} = 1.5\text{ V}$

**6-13. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance**



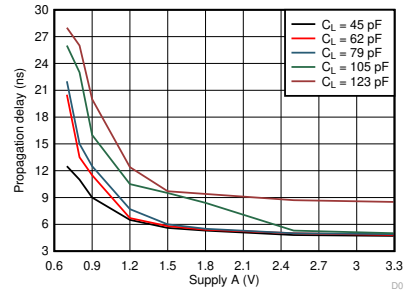
$T_A = 25^\circ\text{C}$   $V_{CCA} = 1.8\text{ V}$

**6-14. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance**



$T_A = 25^\circ\text{C}$   $V_{CCA} = 2.5\text{ V}$

**6-15. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance**



$T_A = 25^\circ\text{C}$   $V_{CCA} = 3.3\text{ V}$

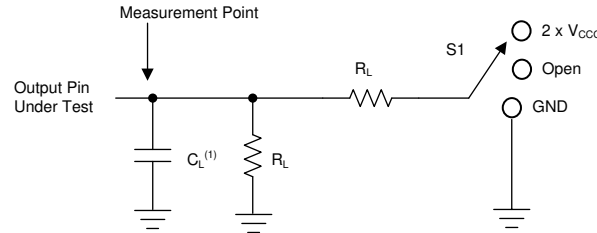
**6-16. Typical Propagation Delay of Low-to-High (B to A) vs Load Capacitance**

## 7 Parameter Measurement Information

### 7.1 Load Circuit and Voltage Waveforms

Unless otherwise noted, all input pulses are supplied by generators having the following characteristics:

- $f = 1 \text{ MHz}$
- $Z_O = 50 \Omega$
- $dv/dt \leq 1 \text{ ns/V}$

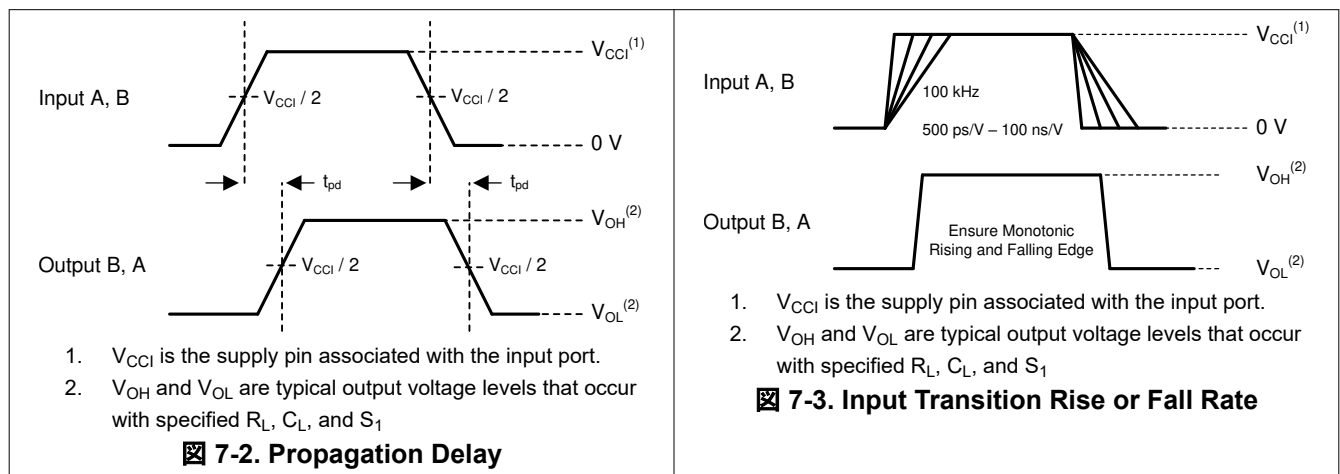


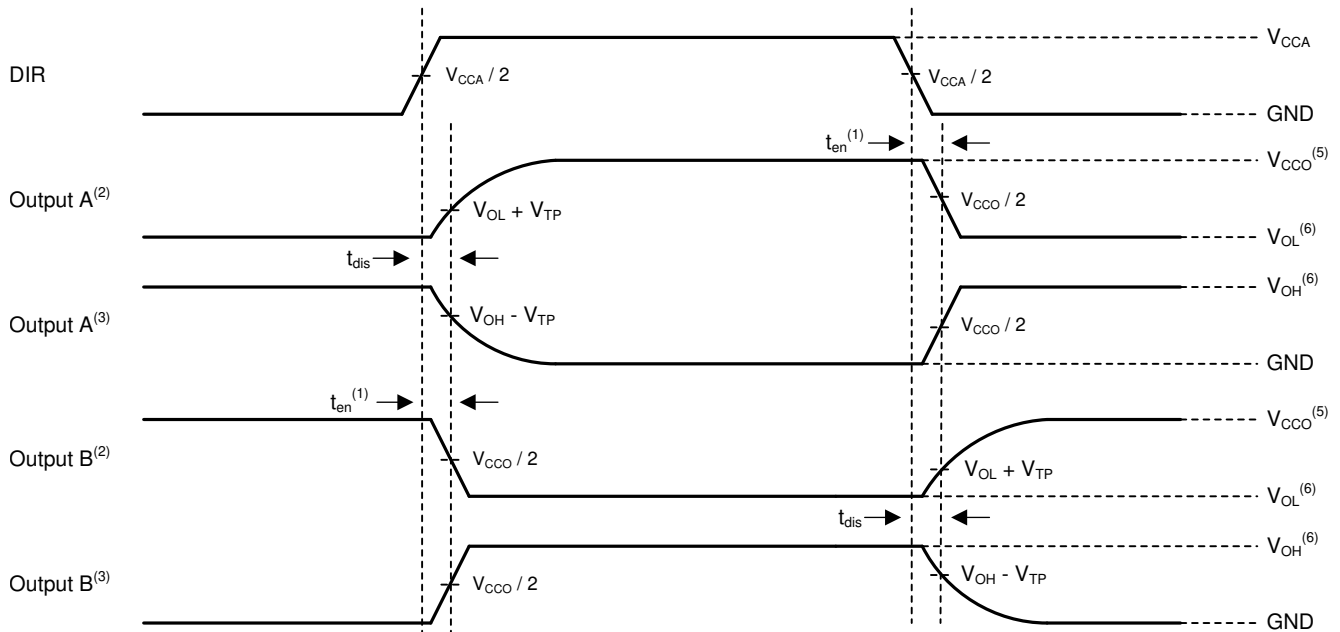
A.  $C_L$  includes probe and jig capacitance.

7-1. Load Circuit

表 7-1. Load Circuit Conditions

Parameter	$V_{CCO}$	$R_L$	$C_L$	$S_1$	$V_{TP}$
$\Delta t/\Delta v$ Input transition rise or fall rate	0.65 V – 3.6 V	1 M $\Omega$	15 pF	Open	N/A
$t_{pd}$ Propagation (delay) time	1.1 V – 3.6 V	2 k $\Omega$	15 pF	Open	N/A
	0.65 V – 0.95 V	20 k $\Omega$	15 pF	Open	N/A
$t_{en}, t_{dis}$ Enable time, disable time	3 V – 3.6 V	2 k $\Omega$	15 pF	$2 \times V_{CCO}$	0.3 V
	1.65 V – 2.7 V	2 k $\Omega$	15 pF	$2 \times V_{CCO}$	0.15 V
	1.1 V – 1.6 V	2 k $\Omega$	15 pF	$2 \times V_{CCO}$	0.1 V
	0.65 V – 0.95 V	20 k $\Omega$	15 pF	$2 \times V_{CCO}$	0.1 V
$t_{en}, t_{dis}$ Enable time, disable time	3 V – 3.6 V	2 k $\Omega$	15 pF	GND	0.3 V
	1.65 V – 2.7 V	2 k $\Omega$	15 pF	GND	0.15 V
	1.1 V – 1.6 V	2 k $\Omega$	15 pF	GND	0.1 V
	0.65 V – 0.95 V	20 k $\Omega$	15 pF	GND	0.1 V





1. Illustrative purposes only. Enable Time is a calculation as described in the data sheet.
2. Output waveform on the condition that input is driven to a valid Logic Low.
3. Output waveform on the condition that input is driven to a valid Logic High.
4.  $V_{CCI}$  is the supply pin associated with the input port
5.  $V_{CCO}$  is the supply pin associated with the output port.
6.  $V_{OH}$  and  $V_{OL}$  are typical output voltage levels that occur with specified  $R_L$ ,  $C_L$ , and  $S_1$

**7-4. Disable and Enable Time**

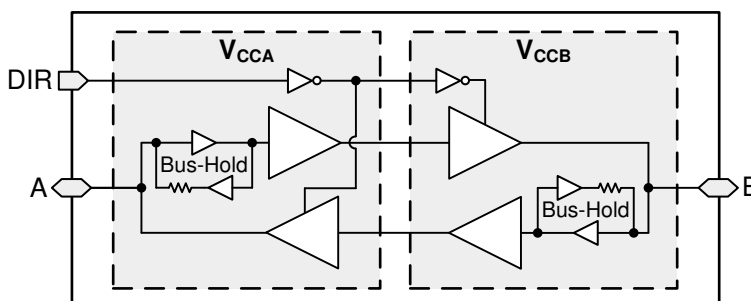


## 8 Detailed Description

### 8.1 Overview

The SN74AXCH1T45 is single-bit, dual-supply, noninverting voltage level translator. Pin A and the direction control pin are referenced to  $V_{CCA}$  logic levels and pin B is referenced to  $V_{CCB}$  logic levels, as depicted in . The A port can accept I/O voltages ranging from 0.65 V to 3.6 V, and the B port can accept I/O voltages from 0.65 V to 3.6 V. A logic high on the DIR pin enables data transmission from A to B and a logic low on the DIR pin enables data transmission from B to A.

### 8.2 Functional Block Diagram



8-1. Functional Block Diagram

### 8.3 Feature Description

#### 8.3.1 Standard CMOS Inputs

Standard CMOS inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the [Electrical Characteristics](#). The worst case resistance is calculated with the maximum input voltage, given in the [Absolute Maximum Ratings](#), and the maximum input leakage current, given in the [Electrical Characteristics](#), using ohm's law ( $R = V \div I$ ).

Signals applied to the inputs need to have fast edge rates, as defined by  $\Delta t/\Delta v$  in [Recommended Operating Conditions](#) to avoid excessive current consumption and oscillations. If a slow or noisy input signal is required, a device with a Schmitt-trigger input should be used to condition the input signal prior to the standard CMOS input.

#### 8.3.2 Balanced High-Drive CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The high drive capability of this device creates fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. The electrical and thermal limits defined in the [Absolute Maximum Ratings](#) must be followed at all times.

#### 8.3.3 Partial Power Down ( $I_{off}$ )

The inputs and outputs for this device enter a high-impedance state when the device is powered down, inhibiting current backflow into the device. The maximum leakage into or out of any input or output pin on the device is specified by  $I_{off}$  in the [Electrical Characteristics](#).

#### 8.3.4 $V_{CC}$ Isolation

The inputs and outputs for this device enter a high-impedance state when either supply is  $<100\text{mV}$ .

#### 8.3.5 Over-voltage Tolerant Inputs

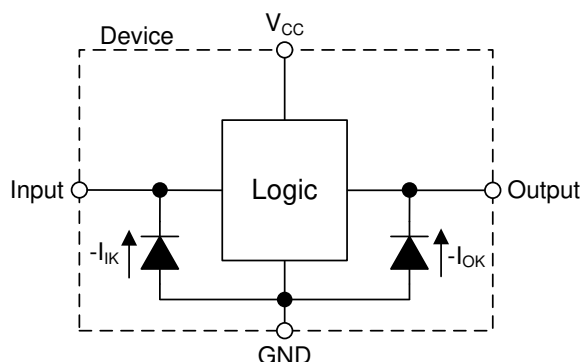
Input signals to this device can be driven above the supply voltage so long as they remain below the maximum input voltage value specified in the [Recommended Operating Conditions](#).

### 8.3.6 Negative Clamping Diodes

The inputs and outputs to this device have negative clamping diodes as depicted in [Figure 8-2](#).

**CAUTION**

Voltages beyond the values specified in the [Absolute Maximum Ratings](#) table can cause damage to the device. The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.



**Figure 8-2. Electrical Placement of Clamping Diodes for Each Input and Output**

### 8.3.7 Fully Configurable Dual-Rail Design

Both the  $V_{CCA}$  and  $V_{CCB}$  pins can be supplied at any voltage from 0.65 V to 3.6 V, making the device suitable for translating between any of the voltage nodes (0.7 V, 0.8 V, 0.9 V, 1.2 V, 1.8 V, 2.5 V and 3.3 V).

### 8.3.8 Supports High-Speed Translation

The SN74AXCH1T45 device can support high data-rate applications. The translated signal data rate can be up to 500 Mbps when the signal is translated from 1.8 V to 3.3 V.

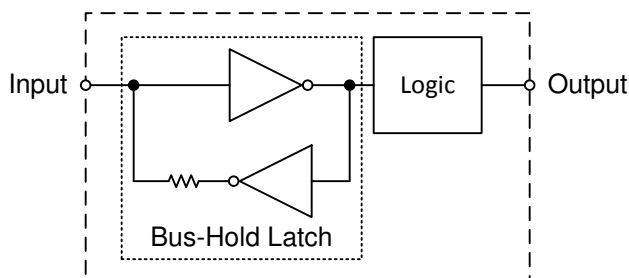
### 8.3.9 Bus-Hold Data Inputs

Each data input on this device includes a weak latch that maintains a valid logic level on the input. The state of these latches is unknown at startup and remains unknown until the input has been forced to a valid high or low state. After data has been sent through a channel, the latch then maintains the previous state on the input if the line is left floating. It is not recommended to use pull-up or pull-down resistors together with a bus-hold input, as it may cause undefined inputs to occur which leads to excessive current consumption.

Bus-hold data inputs prevent floating inputs on this device. The [Implications of Slow or Floating CMOS Inputs](#) application report explains the problems associated with leaving CMOS inputs floating.

These latches remain active at all times, independent of all control signals such as direction control or output enable.

The [Bus-Hold Circuit](#) application report has additional details regarding bus-hold inputs.



**Figure 8-3. Simplified Schematic For Device With Bus-Hold Data Inputs**

## 8.4 Device Functional Modes

表 8-1 lists the device functions for the DIR input.

**表 8-1. Function Table**

INPUT <sup>(1)</sup> DIR	OPERATION
L	B data to A bus
H	A data to B bus

(1) Input circuits of the data I/Os always are active.

## 9 Application and Implementation

### Note

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくこととなります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

### 9.1 Application Information

The SN74AXCH1T45 device can be used in level-translation applications for interfacing devices or systems with one another when they are operating at different interface voltages. The maximum data rate can be up to 500 Mbps when the device translate signals from 1.8 V to 3.3 V.

#### 9.1.1 Enable Times

Calculate the enable times for the SN74AXC1T45 using the following formulas:

$$t_{A\_en} (\text{DIR to A}) = t_{dis} (\text{DIR to B}) + t_{pd} (\text{B to A}) \quad (1)$$

$$t_{B\_en} (\text{DIR to B}) = t_{dis} (\text{DIR to A}) + t_{pd} (\text{A to B}) \quad (2)$$

In a bidirectional application, these enable times provide the maximum delay time from the time the DIR bit is switched until an output is expected. For example, if the SN74AXCH1T45 initially is transmitting from A to B, then the DIR bit is switched; the B port of the device must be disabled ( $t_{dis}$ ) before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay ( $t_{pd}$ ). To avoid bus contention care should be taken to not apply an input signal prior to the output port being disabled ( $t_{dis\ max}$ ).

### 9.2 Typical Applications

#### 9.2.1 Interrupt Request Application

Figure 9-1 shows an example of the SN74AXCH1T45 being used in an application where a system controller flags an interrupt request (IRQ) to the CPU. The system controller determines the direction of the IRQ line to either flag an interrupt to the CPU or allow the CPU to drive data on the line. In this application the controller is operating at 3.3 V while the CPU can be operating as low as 0.65 V.

The SN74AXCH1T45 device is used to ensure that these devices can communicate at the appropriate voltage levels. Because the SN74AXCH1T45 does not have an output-enable ( $\overline{OE}$ ) pin, the system designer should take precautions to avoid bus contention between the CPU and controller when changing directions.

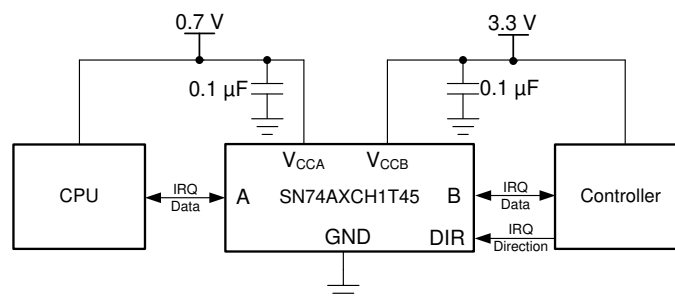


Figure 9-1. Interrupt Request Application

#### 9.2.1.1 Design Requirements

For this design example, use the parameters listed in Table 9-1.

表 9-1. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUES
Input voltage range	0.65 V to 3.6 V
Output voltage range	0.65 V to 3.6 V

9.2.1.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
  - Use the supply voltage of the device that is driving the SN74AXCH1T45 device to determine the input voltage range. For a valid logic-high, the value must exceed the high-level input voltage ( $V_{IH}$ ) of the input port. For a valid logic low the value must be less than the low-level input voltage ( $V_{IL}$ ) of the input port.
- Output voltage range
  - Use the supply voltage of the device that the SN74AXCH1T45 device is driving to determine the output voltage range.

9.2.1.3 Application Curve

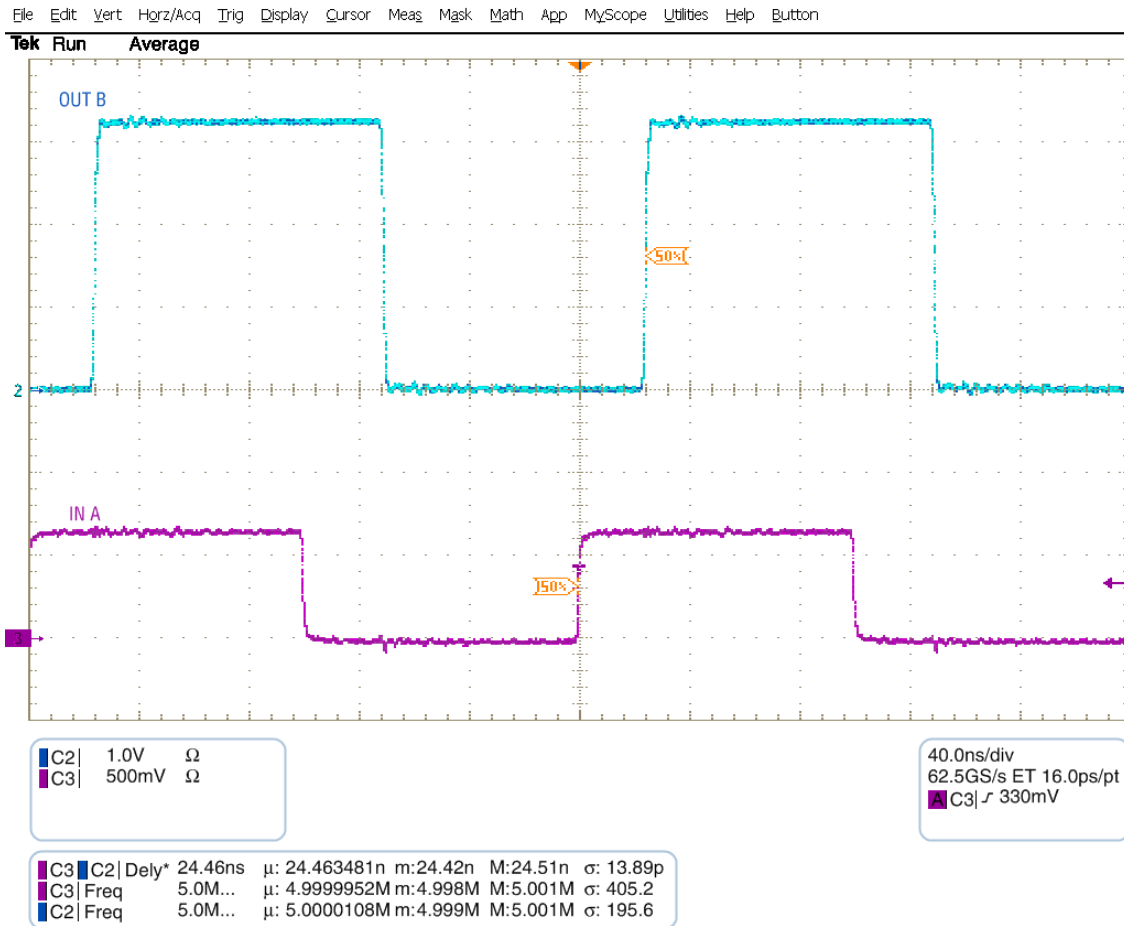


图 9-2. Up Translation at 2.5 MHz (0.7 V to 3.3 V)

## 9.2.2 Universal Asynchronous Receiver-Transmitter (UART) Interface Application

Figure 9-3 shows the SN74AXCH1T45 being used for the two-bit UART interface application. One SN74AXCH1T45 device is used to level shift the voltage and drive the TX from the processor to the GPS Module while a second SN74AXCH1T45 device is used to drive the TX Data line from the GPS Module to the Processor. Devices with bus-hold inputs remove the requirement for external pullup resistors to maintain a valid logic level at the input.

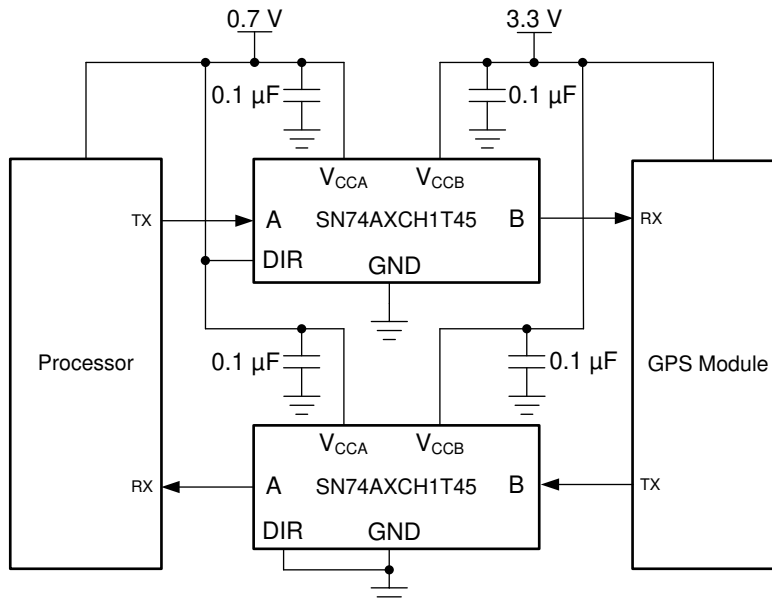


Figure 9-3. UART Interface Application

### 9.2.2.1 Design Requirements

Refer to [Design Requirements](#).

### 9.2.2.2 Detailed Design Procedure

Refer to [Detailed Design Procedure](#).

## 10 Power Supply Recommendations

Always apply a ground reference to the GND pins first. This device is designed for glitch free power sequencing without any supply sequencing requirements such as ramp order or ramp rate.

This device was designed with various power supply sequencing methods in mind to help prevent unintended triggering of downstream devices. For more information regarding the power up glitch performance of the AXC family of level translators, see the [Power Sequencing for AXC Family of Devices](#) application report

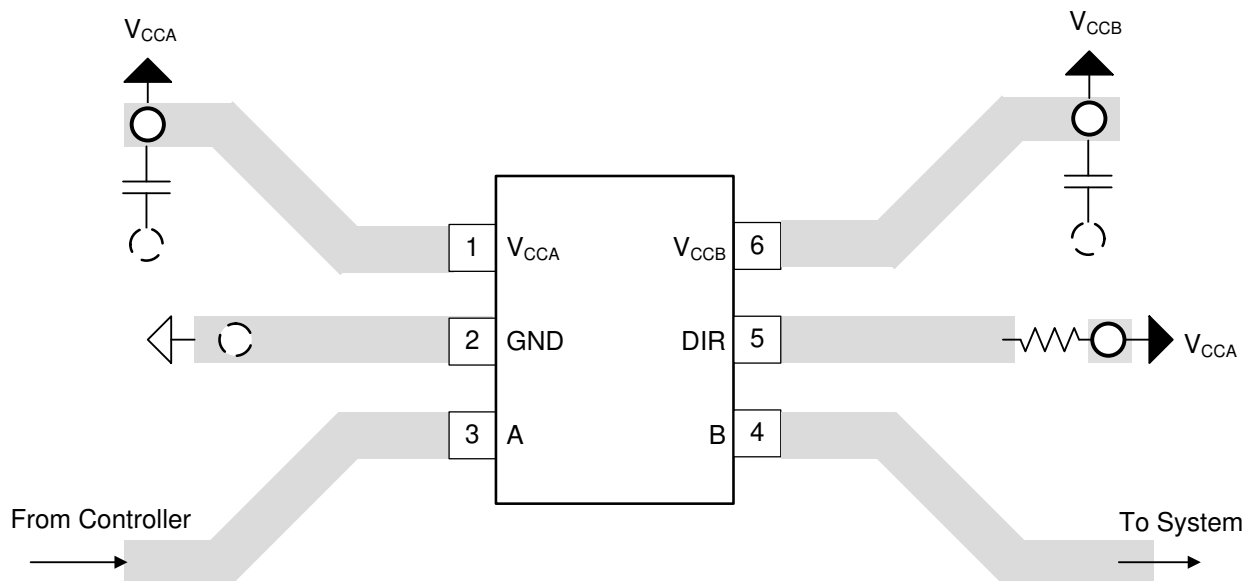
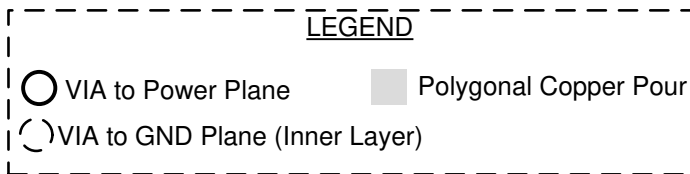
## 11 Layout

### 11.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines are recommended:

- Use bypass capacitors on the power supply pins and place them as close to the device as possible.
- Use short trace lengths to avoid excessive loading.

### 11.2 Layout Example



11-1. PCB Layout Example

## 12 Device and Documentation Support

### 12.1 Documentation Support

For related documentation see the following:

- Texas Instruments, [Evaluate SN74AXC1T45DRL Using a Generic EVM](#) application report
- Texas Instruments, [System Considerations For Using Bus-hold Circuits To Avoid Floating Inputs](#) application report
- Texas Instruments, [Power Sequencing for the AXC Family of Devices](#) application report
- Texas Instruments, [Implications of Slow or Floating CMOS Inputs](#) application report

### 12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 12.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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### 12.4 Trademarks

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### 12.5 静電気放電に関する注意事項



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### 12.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.



## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AXCH1T45DBVR	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	1PNL	<a href="#">Samples</a>
SN74AXCH1T45DCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	1CC	<a href="#">Samples</a>
SN74AXCH1T45DRY2	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	IR	<a href="#">Samples</a>
SN74AXCH1T45DRYR	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	II	<a href="#">Samples</a>
SN74AXCH1T45DTQR	ACTIVE	X2SON	DTQ	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	DM	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

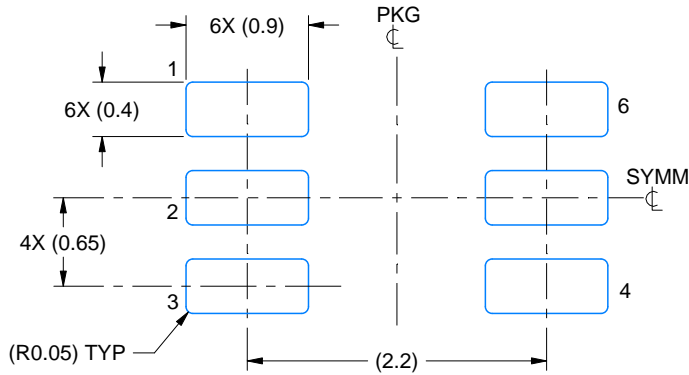
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AXCH1T45DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74AXCH1T45DCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
SN74AXCH1T45DRY2	SON	DRY	6	5000	180.0	9.5	1.6	1.15	0.68	4.0	8.0	Q3
SN74AXCH1T45DRYR	SON	DRY	6	5000	180.0	9.5	1.2	1.65	0.7	4.0	8.0	Q1
SN74AXCH1T45DTQR	X2SON	DTQ	6	3000	180.0	9.5	0.94	1.13	0.5	2.0	8.0	Q2

**TAPE AND REEL BOX DIMENSIONS**

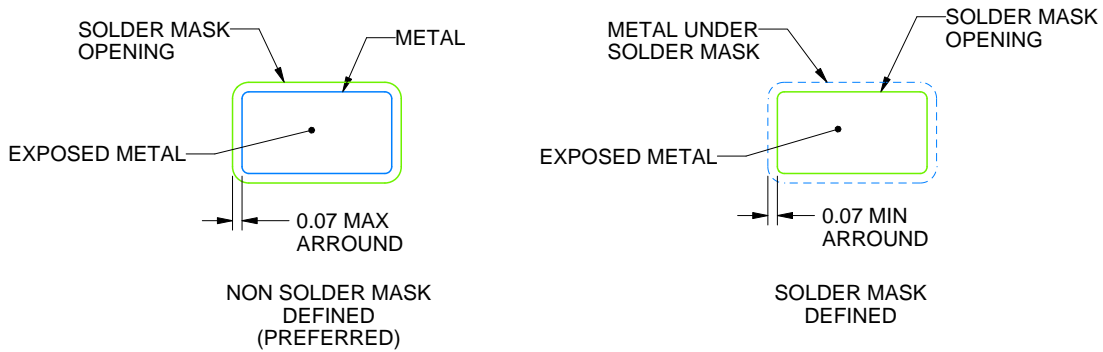

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AXCH1T45DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
SN74AXCH1T45DCKR	SC70	DCK	6	3000	210.0	185.0	35.0
SN74AXCH1T45DRY2	SON	DRY	6	5000	189.0	185.0	36.0
SN74AXCH1T45DRYR	SON	DRY	6	5000	189.0	185.0	36.0
SN74AXCH1T45DTQR	X2SON	DTQ	6	3000	189.0	185.0	36.0





LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:18X

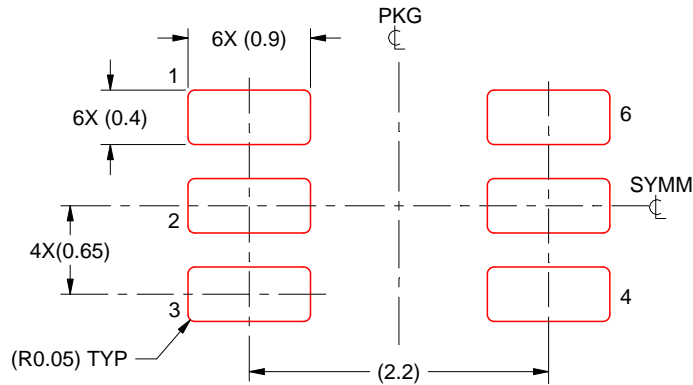


SOLDER MASK DETAILS

4214835/D 11/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE  
BASED ON 0.125 THICK STENCIL  
SCALE:18X

4214835/D 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.



## GENERIC PACKAGE VIEW

**DRY 6**

**USON - 0.6 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4207181/G

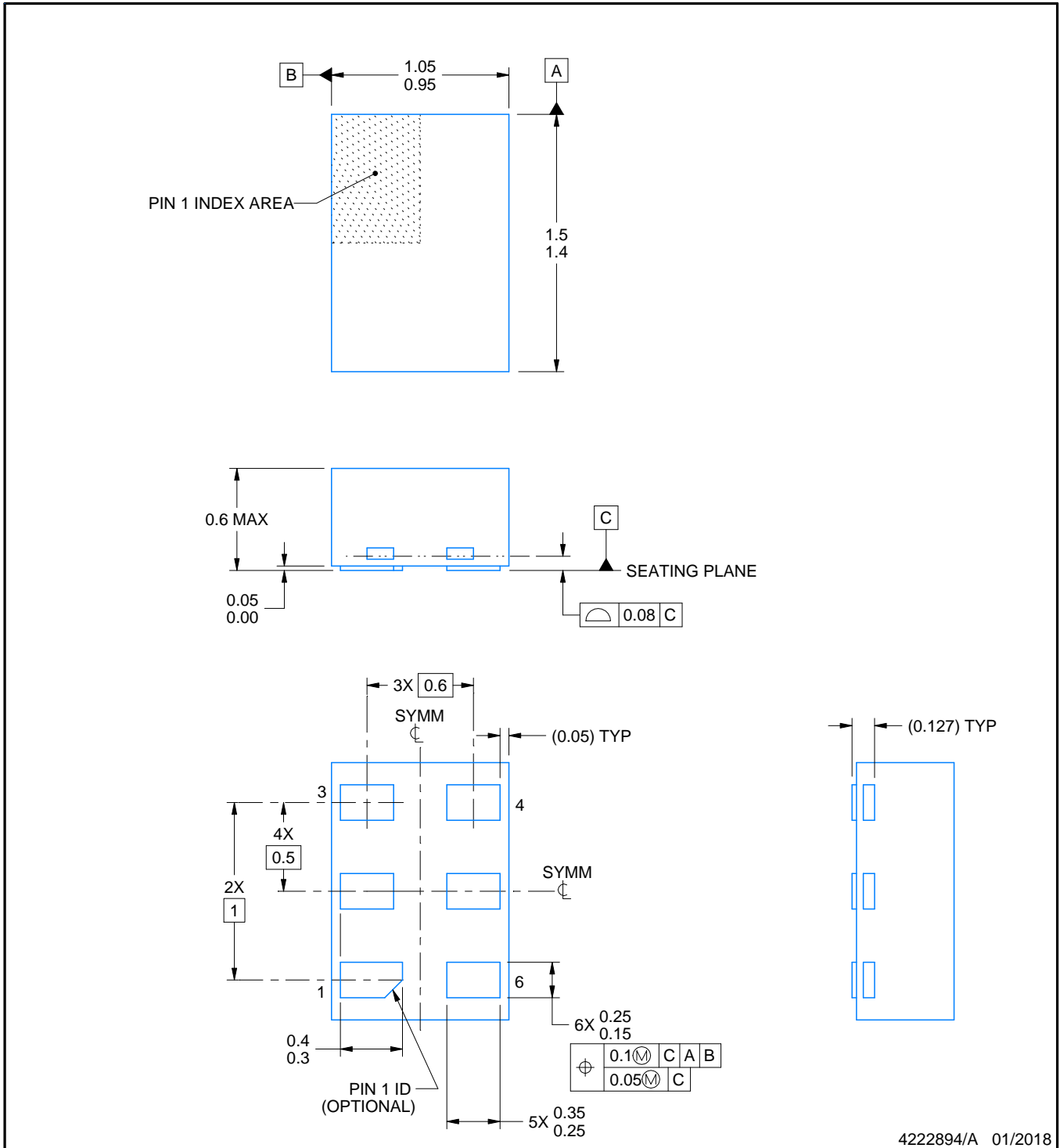
DRY0006A



# PACKAGE OUTLINE

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

DRY0006A

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



**LAND PATTERN EXAMPLE**  
 1:1 RATIO WITH PKG SOLDER PADS  
 EXPOSED METAL SHOWN  
 SCALE:40X



**SOLDER MASK DETAILS**

4222894/A 01/2018

NOTES: (continued)

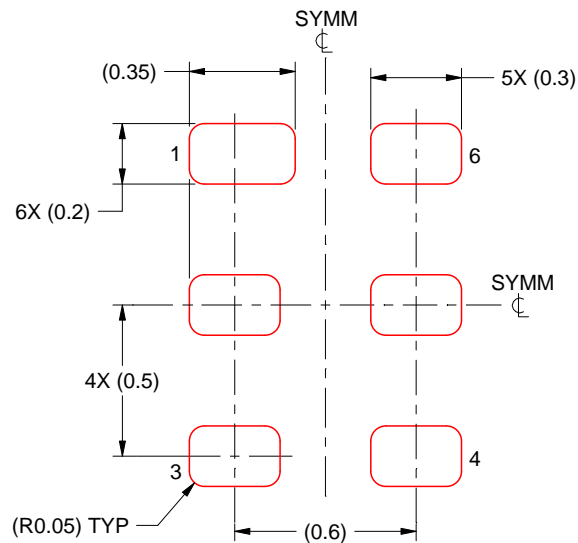
3. For more information, see QFN/SON PCB application report in literature No. SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).

# EXAMPLE STENCIL DESIGN

DRY0006A

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

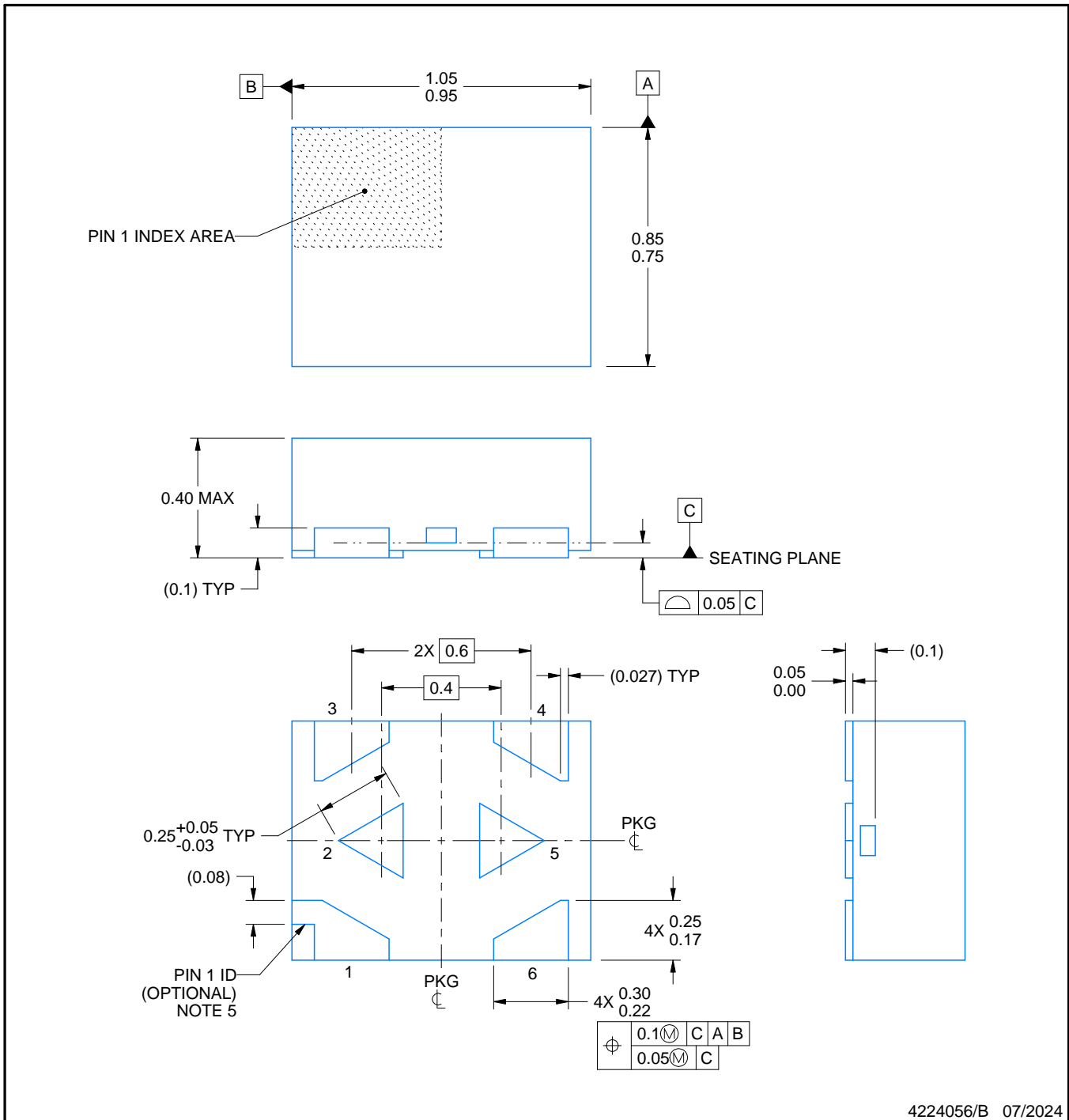


SOLDER PASTE EXAMPLE  
BASED ON 0.075 - 0.1 mm THICK STENCIL  
SCALE:40X

4222894/A 01/2018

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



NOTES:

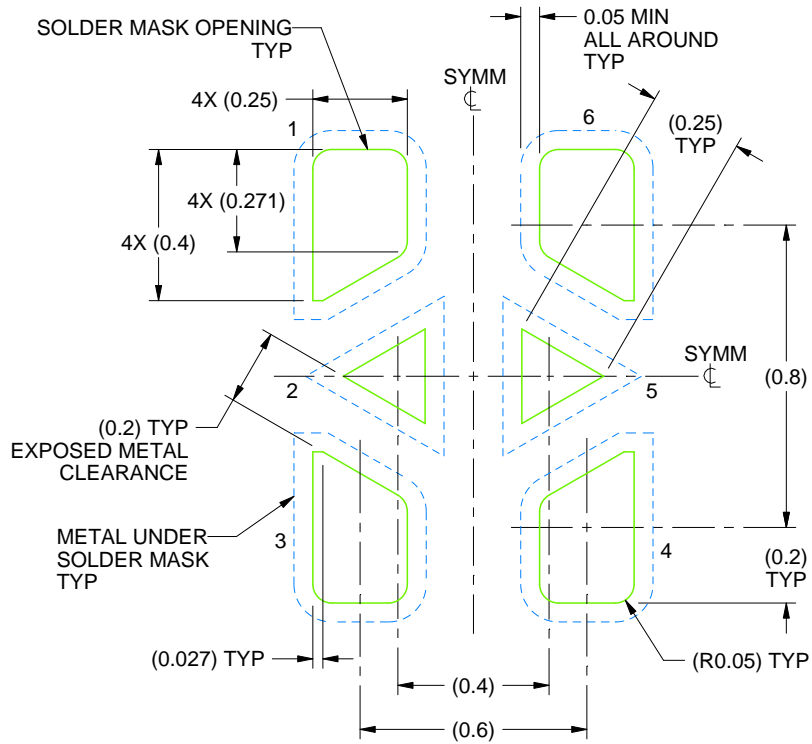
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pads must be soldered to the printed circuit board for optimal thermal and mechanical performance.
4. The size and shape of this feature may vary.
5. Features may not exist. Recommend use of pin 1 marking on top of package for orientation purposes.

# EXAMPLE BOARD LAYOUT

DTQ0006A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
SOLDER MASK DEFINED  
SCALE:50X

4224056/B 07/2024

NOTES: (continued)

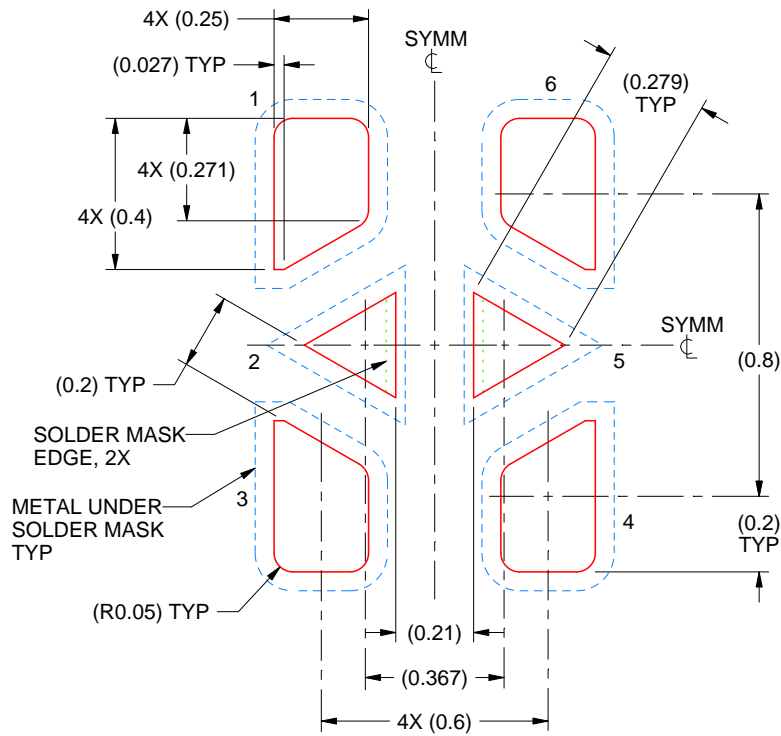
6. This package is designed to be soldered to a thermal pads on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
7. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

# EXAMPLE STENCIL DESIGN

DTQ0006A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.07 mm THICK STENCIL

PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:50X

4224056/B 07/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



# DBV0006A

# PACKAGE OUTLINE

## SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214840/G 08/2024

### NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Reference JEDEC MO-178.



# EXAMPLE BOARD LAYOUT

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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